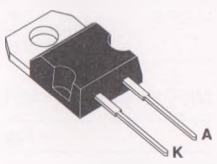
SGS-THOMSON MICROELECTRONICS

BYT 08P-600/800

FAST RECOVERY RECTIFIER DIODES

- HIGH REVERSE VOLTAGE CAPABILITY
- VERY LOW REVERSE RECOVERY TIME
- VERY LOW SWITCHING LOSSES
- LOW NOISE TURN-OFF SWITCHING

Cathode connected to case



TO220AC
(Plastic)

SUITABLE APPLICATIONS

- FREE WHEELING DIODE IN CONVERTERS AND MOTOR CONTROL CIRCUITS
- RECTIFIER IN S.M.P.S.

ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
I_{FRM}	Repetitive Peak Forward Current	$t_p < 10\mu s$	100	A
$I_{F(RMS)}$	RMS Forward Current		16	A
$I_{F(AV)}$	Average Forward Current	$T_{case} = 115°C$ $\delta = 0.5$	8	A
I_{FSM}	Surge non Repetitive Forward Current	$t_p = 10ms$ sinusoidal	50	A
P	Power Dissipation	$T_{case} = 115°C$	17	W
T_{stg} T_j	Storage and Junction Temperature Range		– 40 to + 150	°C

Symbol	Parameter	BYT 08P-		Unit
		600	800	
V_{RRM}	Repetitive Peak Reverse Voltage	600	800	V
V_{RSM}	Non Repetitive Peak Reverse Voltage	640	850	V

THERMAL RESISTANCE

Symbol	Test Conditions	Value	Unit
$R_{th\ (j-c)}$	Junction-case	2	°C/W

ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
I_R	T_j = 25°C	$V_R = V_{RRM}$			35	µA
	T_j = 100°C				2	mA
V_F	T_j = 25°C	I_F = 8A			1.9	V
	T_j = 100°C				1.8	

RECOVERY CHARACTERISTICS

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
t_{rr}	T_j = 25°C	I_F = 1A di_F/dt = – 15A/µs V_R = 30V			120	ns
		I_F = 0.5A I_R=1A I_{rr} = 0.25A			50	

TURN -OFF SWITCHING CHARACTERISTICS (Without Series Inductance)

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
t_{IRM}	di_F/dt = – 32A/µs	V_{CC} = 200V I_F = 8A $L_p \leq$ 0.05µH T_j = 100°C See Figure 1			160	ns
	di_F/dt = – 64A/µs			100		
I_{RM}	di_F/dt = – 32A/µs				4	A
	di_F/dt = – 64A/µs			5		

TURN -OFF OVERVOLTAGE COEFFICIENT - With Series Inductance

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
$C = \frac{V_{RP}}{V_{CC}}$	T_j = 100°C di_F/dt = – 8A/µs	V_{CC} = 150V $I_F = I_{F(AV)}$ L_p = 12µH See figure 2			4	

To evaluate the conduction losses use the following equations :

$V_F = 1.47 + 0.04\ I_F$ $\qquad P = 1.47 \times I_{F(AV)} + 0.04\ I_F{}^2{}_{(RMS)}$

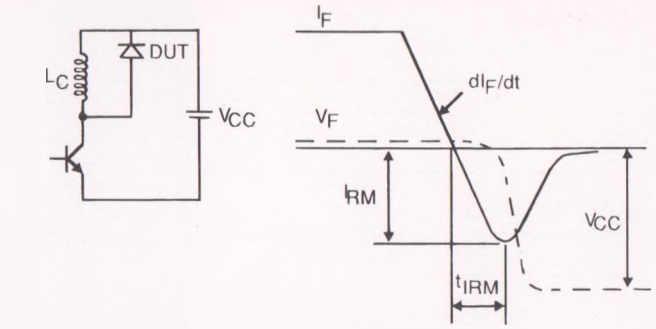


Figure 1 : Turn-off switching characteristics (without series inductance).

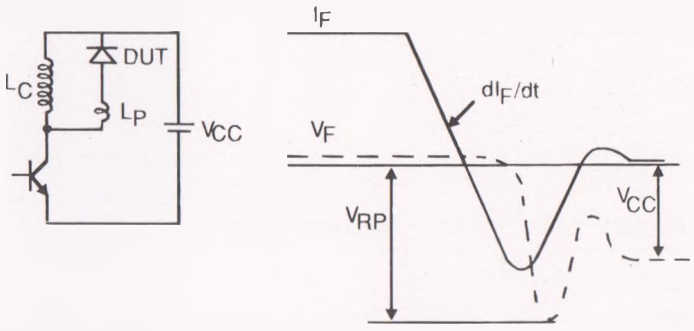


Figure 2 : Turn-off switching characteristics (with series inductance).